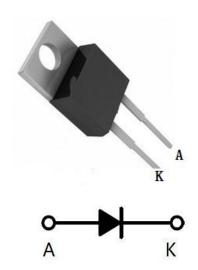


FRED Ultrafast Soft Recovery Diode, 30A

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity
- Epitaxial chip construction



Product Summary		
V_R	200 V	
lf(AV)	30A	
t _{rr}	23 ns	

Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings				
Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	V_{RRM}		200	V
Continuous forward current	lf(AV)	Tc =110°C	30	
Single pulse forward current	I _{FSM}	Tc =25°C	300	А
Maximum repetitive forward current	I _{FRM}	Square wave, 20kHZ	240	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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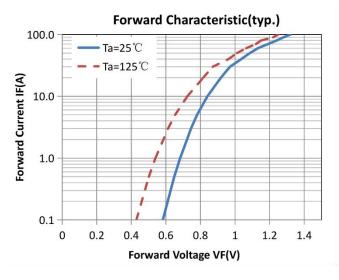


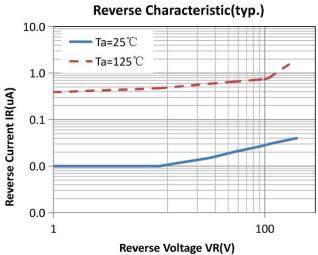
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage Blocking voltage	V _{BR} ,	I _R =100μA	200			
Forward voltage (Per Diode)		I _F =30 A		0.97	1.20	V
	V _F	I _F =30 A, Tj =125°C		0.87	1.00	
Reverse leakage		VR= VRRM			10	
current(Per Diode)	I _R	Tj=150°C, V _R =200V			100	μΑ
Reverse recovery time(Per Diode)	+	I _F =0.5A, I _R =1A, I _{RR} =0.25A		35	45	nc
	t _{rr}	I _F =1A,V _R =30V, di/ <i>dt</i> =200A/us		23	40	ns

Thermal characteristics

Paramter	Symbol	Тур	Units
Junction-to-Case	$R_{ heta JC}$	2.0	°C/W

Electrical performance



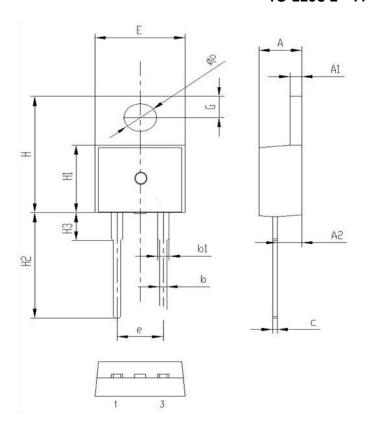


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Package Information

TO-220C-2 PACKAGE



Symbol	Dimensions(millimeters	
Symbol	Min.	Max.
Α	4.35	4.75
A1	2.30	2.70
A2	0.40	0.80
A3	2.10	2.50
b	0.60	1.00
b1	1.00	1.40
С	0.30	0.70
е	4.60	5.40
Е	9.80	10.2
E1	6.30	6.70
Н	15.6	16.0
H1	8.80	9.20
H2	12.9	13.5
H3	3.10	3.50
G	3.10	3.50
ΦР	3.10	3.50

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